

PWM Control Circuit

(compatible to TL494)

Description

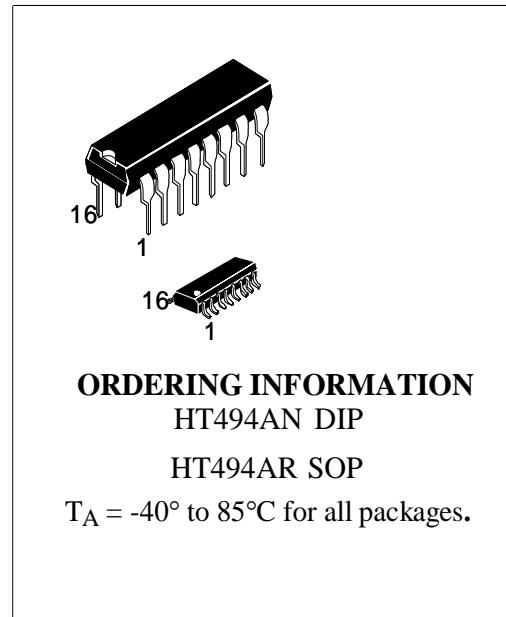
The HT494A incorporates on a single monolithic chip all the function required in the development of a pulse - width modulation control circuits. Designed primarily for power supply control , the HT494A contains an on-chip 5 volt regulator, two error amplifiers, adjustable oscillator, dead time control comparator, pulse-steering flip-flop, and output control circuitry. The uncommitted output transistors provide either common-emitter or emitter-follower output capability. Push-pull or single-ended output operation may be selected through the output-control function. The architecture of the HT494A prohibits the possibility of either output being pulsed twice during push-pull operation.

Features

- Complete PWM Power Control Circuitry
- Uncommitted Outputs for 200 mA Sink or Source
- Output Control Selects Single-Ended or Push-Pull Operation
- Internal Circuitry Prohibits Double Pulse at Either Output
- Internal Regulator Provides a Stable 5V Reference Supply
- Variable Dead-Time Provides Control Over Whole Range

Function Table

Output Control	Output Function
Grounded	Single-ended or Parallel Output
At V _{ref}	Normal Operation Push-Pull Operation

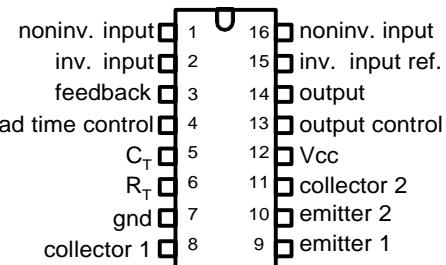


ORDERING INFORMATION

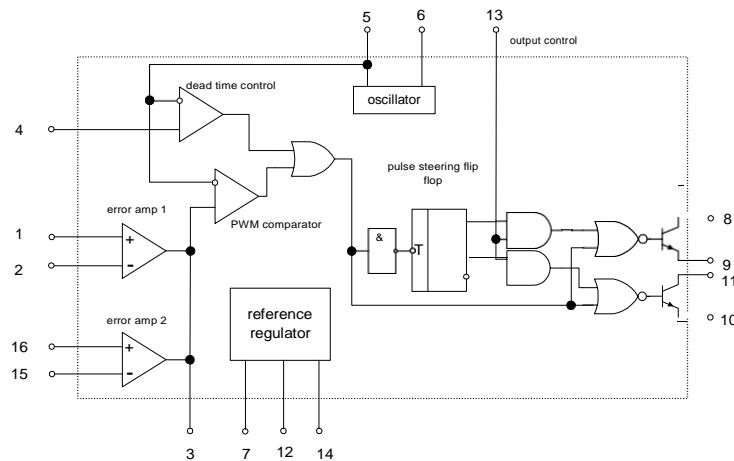
HT494AN DIP

HT494AR SOP

T_A = -40° to 85°C for all packages.



Block Diagram



Standard deviation is derived from the formula

$$\sigma = \sqrt{\frac{\sum_{n=1}^N (X_n - \bar{X})^2}{N-1}}$$

RECOMMENDED OPERATION CONDITIONS

PARAMETER	MIN	MAX	UNIT
Supply Voltage	7	40	V
Amplifier Input Voltage	-0.3	Vcc-2	V
Collector Output Voltage		40	V
Collector Output Current (Each Transistor)		200	mA
Current Into Feedback Terminal		0.3	mA
Timing Capacitor	0.47	10000	nF
Timing Resistor	1.8	500	kΩ
Oscillator Frequency	1	300	kHz
Operating Temperature	-20	85	°C

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	41V
Amplifier Input Voltage	Vcc+0.3V
Collector Output Voltage	41V
Continuous Total Dissipation at (or below) 25°C	1000mW
Operating Free-Air Temperature Range	-20 to 85°C
Storage Temperature Range	-65 to 150°C
Collector Output Current	250mA

Electrical Characteristics (Temperature -20...85°C, Vcc=15V, f=10kHz)

REFERENCE SECTION

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Output voltage (V_{ref})	$I_o=1\text{mA}$	4.75	5.25	V
Input regulation	$Vcc=7\text{V to }40\text{V}, Ta=25^\circ\text{C}$		25	mV
Output regulation	$I_o=1\text{ to }10\text{mA}, Ta=25^\circ\text{C}$		15	mV
Output voltage change with temperature	$Ta=-20^\circ\text{C to }85^\circ\text{C}$		1	%
Short circuit output current	V_{ref}		60	mV

DEAD TIME CONTROL SECTION

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Input bias current (pin 4)	$Vi=0\text{V to }5.25\text{V}$		-10	μA
Maximum duty cycle (each output)	$V_{i(\text{pin 4})}=0\text{V}$	45		%
Input threshold voltage (pin 4)	zero duty cycle		3.3	V
	maximum duty cycle	0		V

ERROR AMPLIFIERS SECTION

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Input offset voltage	$V_{o(\text{pin 3})}=2.5$		10	mV
Input offset current	$V_{o(\text{pin 3})}=2.5$		250	nA
Input bias current	$V_{o(\text{pin 3})}=2.5$		1	μA
Common mode input voltage range	$Vcc=7\text{ to }40\text{V}$	-0.3		V
Open loop voltage amplification	$\Delta Vo=3\text{V}, Vo=0.5\text{ to }3.5\text{V}$	70		dB
Unity-gain bandwidth		100		kHz
Common mode rejection ratio	$Vcc=40\text{V}, Ta=25^\circ\text{C}$	65		dB
Output sink current (pin 3)	$V_{ID}=-15\text{mV to }-5\text{V}, V_{o(\text{pin 3})}=0.7\text{V}$	0.3		mA
Output source current (pin 3)	$V_{ID}=15\text{mV to }5\text{V}, V_{o(\text{pin 3})}=3.5\text{V}$	-2		mA

DISSIPATION RATING TABLE

PACKAGE	$T_A = 25^\circ\text{C}$ POWER RATING	OPERATING FACTOR	DERATE ABOVE T_A	$T_A=70^\circ\text{C}$ POWER RATING	$T_A=85^\circ\text{C}$ POWER RATING
D N	900 mW 1000 mW	7.6 mW/°C 9.2 mW/°C	25°C 41°C	608 mw 736 mW	494 mW 598 mW

PWM COMPARATOR SECTION

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Input threshold voltage (pin 3)	zero duty cycle		4.5	V
Input sink current (pin 3)	$V_{o(pin\ 3)}=0.7V$	0.3		mA

SWITCHING CHARACTERISTICS

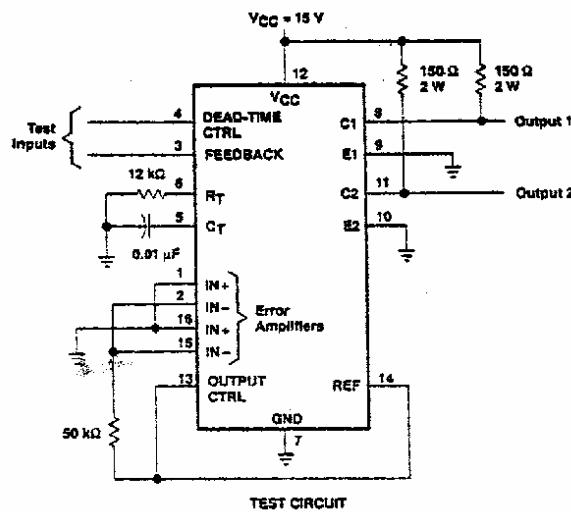
PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Output voltage rise time	Common emitter		200	ns
Output voltage fall time	configuration		100	ns
Output voltage rise time	Emitter-follower		200	ns
Output voltage fall time	configuration		100	ns

OUTPUT SECTION

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Collector off-state current	$V_{CE}=40V, V_{CC}=40V$		100	μA
Emitter off-state current	$V_{CC}=V_C=40V, V_E=40V$		-100	μA
Collector - Emitter	Common emitter		1.3	V
saturation voltage	Emitter-follower		2.5	V
Output control input current	$V_i=V_{ref}$		3.5	mA

OSCILLATOR SECTION

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Frequency	$C_T=0.01\mu F, R_T=12k\Omega$		30	kHz
Standard deviation of frequency	All Values of V_{CC}, C_T, R_T, T_a are constant		30	%
Frequency change with voltage	$V_{CC}=7V$ to $40V, T_a=25^\circ C$		10	%
Frequency change with temperature	$C_T=0.01\mu F, R_T=12k\Omega,$		2	

PARAMETER MEASUREMENT INFORMATION


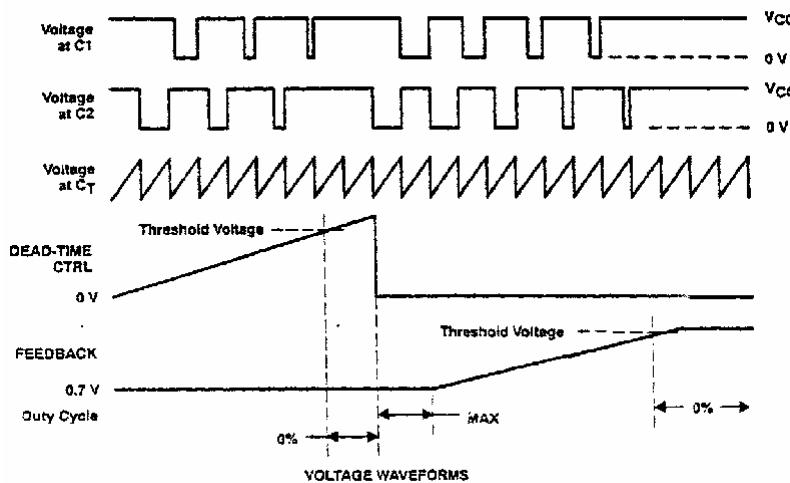
 TEST CIRCUIT


Figure 1. Operational Test Circuit and Waveforms

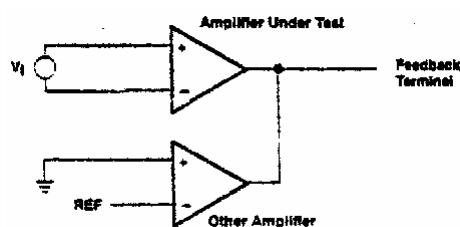


Figure 2. Amplifier Characteristics

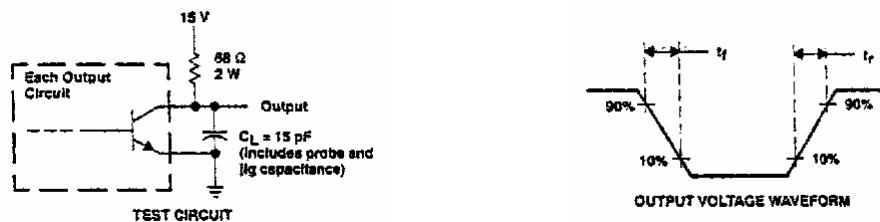


Figure 3. Common-Emitter Configuration

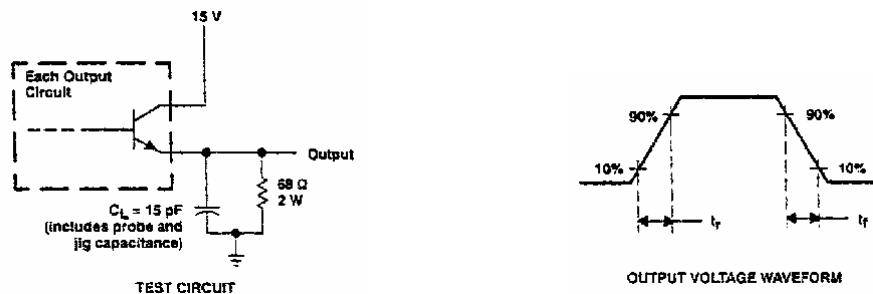


Figure 4. Emitter-Follower Configuration

TYPICAL CHARACTERISTICS
OSCILLATOR FREQUENCY AND FREQUENCY VARIATION
VS
TIMING RESISTANCE

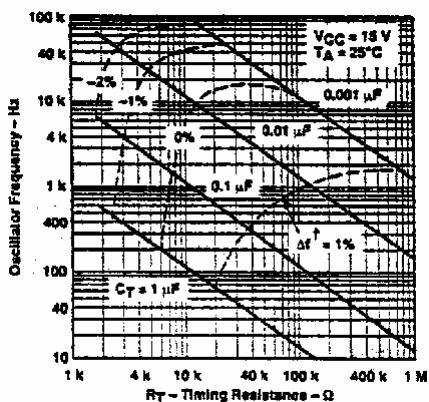


Figure 5

AMPLIFIER VOLTAGE AMPLIFICATION vs FREQUENCY

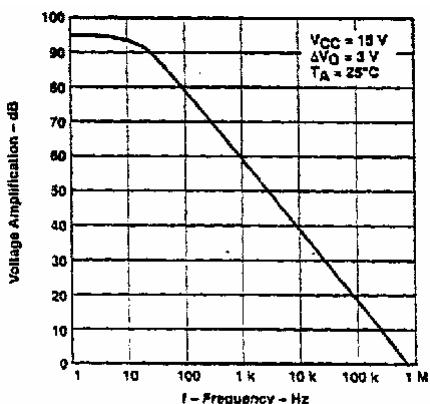


Figure 6